Vishay Semiconductors

High Performance Schottky Rectifier, 100 A





PowerTab[®]

PRIMARY CHARACTERISTICS				
I _{F(AV)}	100 A			
V _R	100 V			
V _F at I _F	0.82 V			
I _{RM}	180 mA at 125 °C			
E _{AS}	9 mJ			
T _J max.	175 °C			
Package	PowerTab [®]			
Circuit configuration	Single			

www.vishay.com

FEATURES

- 175 °C max. operating junction temperature
- High frequency operation
- Low forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ100HF4 Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS VALUES UN				
	Rectangular waveform	100	А		
I _{F(AV)}	T _C	124	°C		
V _{RRM}		100	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	6300	А		
VF	100 A _{pk} (typical)	0.77	V		
VF	TJ	125	°C		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-100BGQ100HF4	UNITS		
Maximum DC reverse voltage	V _R	100	V		
Maximum working peak reverse voltage	V _{RWM}	100	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_C = 124 °C	C, rectangular waveform	100	А
Maximum peak one cycle	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	6300	А
non-repetitive surge current		10 ms sine or 6 ms rect. pulse		800	~
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4.5 \text{ mH}$ 9		mJ	
Repetitive avalanche current	I _{AR}	$\begin{tabular}{ c c c c } \hline Current decaying linearly to zero in 1 \mbox{μs} \\ \hline Frequency limited by T_J maximum V_A = 1.5 x V_B typical $$2$ A $$$		А	

 Revision: 16-Jan-2019
 1
 Document Number: 93803

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



RoHS

COMPLIANT



VS-100BGQ100HF4

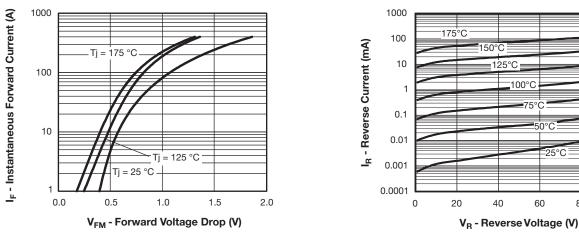
Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES		UNITS	
FADAIVIETED	STWDOL	1231 00	NDITIONS	TYP.	MAX.	UNITS
		50 A	T.I = 25 °C	0.83	0.86	V
Forward voltage drop	V _{FM} ⁽¹⁾	100 A	IJ=25 C	1.01	1.08	
r orward voltage drop		50 A	T.I = 125 °C	0.66	0.7	
		100 A	1J = 125 C	0.77	0.82	
Reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 25 \ ^\circ C$	V _R = Rated V _R	22	300	μA
neverse leakage current	IRM (**	T _J = 125 °C		14	18	mA
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal ran	13	20	pF	
Typical series inductance	L _S	Measured from tab to mounting plane 3.5			.5	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000			V/µs	

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - ME	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER SYMBOL		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction an temperature range	d storage	T _J , T _{Stg}	T _J , T _{Stg}		°C	
Maximum thermal res junction to case	sistance,	R _{thJC}	DC operation	0.50	°C/W	
Typical thermal resist case to heatsink	ance,	R _{thCS}	R _{thCS} Mounting surface, smooth and greased		0/11	
Approximate weight				5	g	
Approximate weight				0.18	oz.	
minimum				1.2 (10)	N·m	
Mounting torque -	maximum			2.4 (20)	(lbf · in)	
Marking device			Case style PowerTab [®]	100BGQ100H		



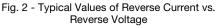


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Revision: 16-Jan-2019

2

Document Number: 93803

100

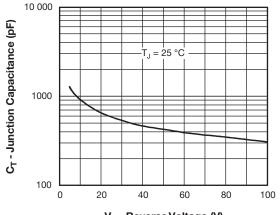
80

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

VS-100BGQ100HF4

Vishay Semiconductors





V_R - Reverse Voltage (V)

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

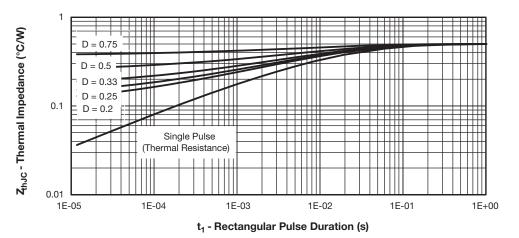
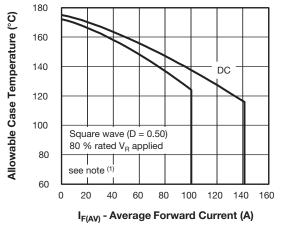
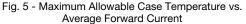


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





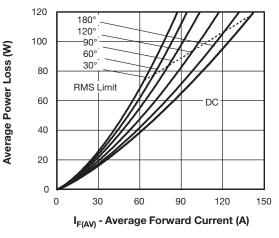


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ 6); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 16-Jan-2019

3

Document Number: 93803

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;





Vishay Semiconductors

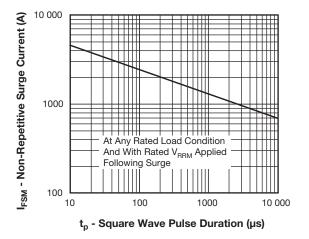
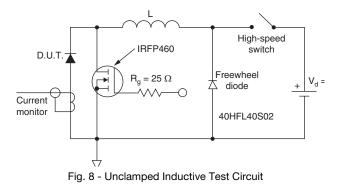


Fig. 7 - Maximum Non-Repetitive Surge Current



ORDERING INFORMATION TABLE

Device code	VS-	100	BGQ	100	н	F4
	1	2	3	4	5	6
	1 - 2 -		hay Serr rrent rati			
	3 -	Ess	ential pa	art numb	ber	
	4 -	Vol	tage rati	ng (100	= 100 V	()
	5 -	H =	AEC-Q	101 qua	lified	
	6 -	En	/ironmer	ntal digit	:	

- F4 = RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-100BGQ100HF4	25	375	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95240</u>				
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			
SPICE model	www.vishay.com/doc?96588			

 Revision: 16-Jan-2019
 4
 Document Number: 93803

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

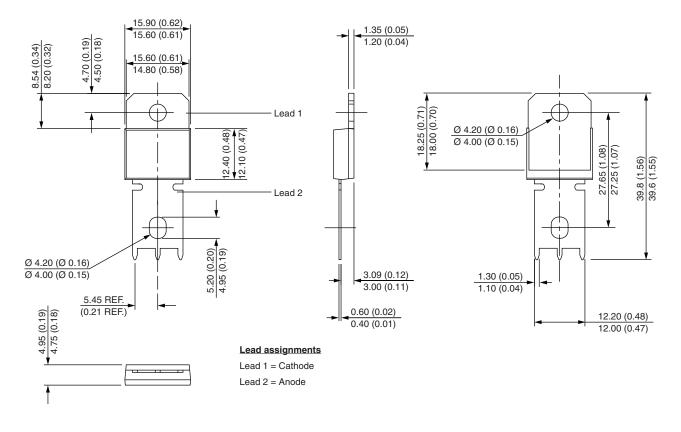
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

PowerTab[®]

DIMENSIONS in millimeters (inches)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRA140TRPBF MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573